

Ultrafast Recovery Rectifier

MUR30120

FEATURES

- Ultrafast Recovery Time
- Low Forward Voltage
- Low Leakage Current
- 175°C Operating Junction Temperature
- High Temperature Glass Passivated Junction

MECHANICAL CHARACTERISTICS

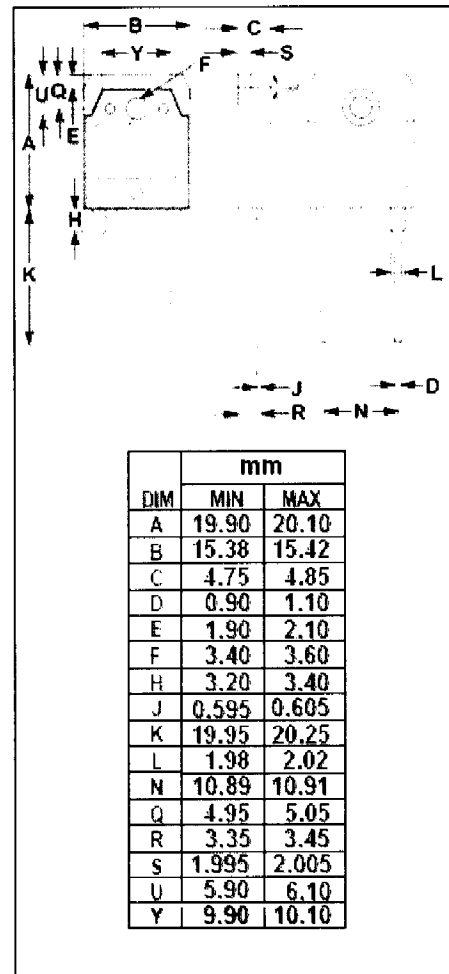
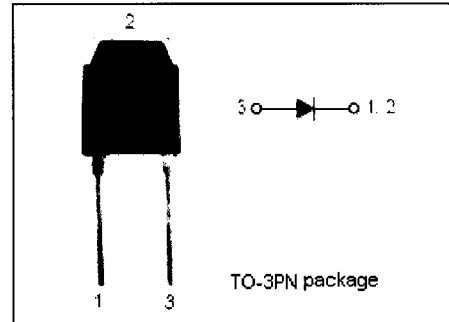
- Case: Epoxy, Molded
- Finish: All External Surfaces Corrosion Resistant and Terminal Leads are Readily Solderable
- Lead Temperature for Soldering Purposes: 260°C Max. for 10 Seconds

APPLICATIONS

- Designed for use in switching power supplies, inverters and as free wheeling diodes.

ABSOLUTE MAXIMUM RATINGS(T_a=25°C)

SYMBOL	PARAMETER	VALUE	UNIT
V _{RRM} V _{RWM} V _R	Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	1200	V
I _{F(AV)}	Average Rectified Forward Current (Rated V _R)	30	A
I _{FRM}	Peak Repetitive Forward Current (Rated V _R , Square Wave, 20kHz)	30	A
I _{FSM}	Nonrepetitive Peak Surge Current (Surge applied at rated load conditions half-wave, single phase, 60Hz)	300	A
T _J	Junction Temperature	-65~175	°C
T _{stg}	Storage Temperature Range	-65~175	°C



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Ultrafast Recovery Rectifier**MUR30120****THERMAL CHARACTERISTICS**

SYMBOL	PARAMETER	MAX	UNIT
R_{thj-c}	Thermal Resistance, Junction to Case	1.4	$^{\circ}C/W$

ELECTRICAL CHARACTERISTICS ($T_a=25^{\circ}C$) (Pulse Test: Pulse Width=300 μ s, Duty Cycle \leq 2%)

SYMBOL	PARAMETER	CONDITIONS	MAX	UNIT
V_F	Maximum Instantaneous Forward Voltage	$I_F=30A$	2.68	V
I_R	Maximum Instantaneous Reverse Current	$V_{RRM}=1200V$	20	μA
t_{rr}	Maximum Reverse Recovery Time	$I_F=0.5A, I_R=1A, I_{rr}=0.25A$	100	ns